Vishay Semiconductors

AUTOMOTIVE

COMPLIANT HALOGEN

FREE

Ultrafast Rectifier, 2 A FRED Pt®

Oliralasi neciller, 2 A FNE



MicroSMP (DO-219AD)

Anode O Cathode

DESIGN SUPPORT TOOLS AVAILABLE



PRIMARY CHARACTERISTICS					
I _{F(AV)}	2 A				
V_{R}	100 V, 200 V				
V _F at I _F	0.82 V				
t _{rr} (typ.)	33 ns				
I _{FSM}	30 A				
T _J max.	175 °C				
Package	MicroSMP (DO-219AD)				
Circuit configuration	Single				

FEATURES

- · Very low profile typical height of 1.0 mm
- · Ideal for automated placement
- · Low forward voltage drop, low power losses
- · Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- For PFC, CRM snubber operation
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATION

For use in high frequency, freewheeling, DC/DC converters, PFC, and in snubber industrial and automotive applications.

MECHANICAL DATA

Case: MicroSMP (DO-219AD)

Molding compound meets UL 94 V-0 flammability rating

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 33-N102, meets JESD 201 class 2

whisker test

Polarity: color band denotes cathode end

ABSOLUTE MAXIMUM RATINGS							
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Peak repetitive reverse voltage -	VS-2EQH01HM3	- V _{RRM}		100	V		
	VS-2EQH02HM3			200			
Average rectified forward current		I _{F(AV)}	T _M = 137 °C	2	^		
Non-repetitive peak surge current		I _{FSM}	T _J = 25 °C, 10 ms sine pulse	30	Α		
Operating junction and storage temperatures		T _J , T _{Stg}		-55 to +175	°C		

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER		SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage,	Breakdown voltage, VS-2EQH01HM3	V _{BR} , V _R	I _R = 100 μA	100	-	-	V
blocking voltage	VS-2EQH02HM3			200			
Forward voltage		V _F	I _F = 2 A	-	0.96	1.05	
			I _F = 2 A, T _J = 150 °C	-	0.82	0.84	
Reverse leakage current		I_	$V_R = V_R$ rated	-	1	μA	
neverse leakage current		I _R	T _J = 150 °C, V _R = V _R rated	-	-	25	μΑ
Junction capacitance		C _T	V _R = 200 V	-	6	-	pF

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DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS	
		$I_F = 1.0 \text{ A}, dI_F/dt = 50 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		-	33	-	
Reverse recovery time	t _{rr}	$I_F = 0.5 \text{ A}, I_R = 1 \text{ A}, I_{rr} = 0.25 \text{ A}$		-	-	23	
		T _J = 25 °C		-	19	-	ns
		T _J = 125 °C		-	33	-	
Peak recovery current I _{RRM}		T _J = 25 °C	$I_F = 2 \text{ A}$ $dI_F/dt = 200 \text{ A/}\mu\text{s}$ $V_R = 100 \text{ V}$	-	1.7	-	A nC
	IRRM	T _J = 125 °C		-	2.5	-	
Reverse recovery charge Q _{rr}	0	T _J = 25 °C		-	15	-	
	Q _{rr}	T _J = 125 °C		-	34	-	

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and s range	storage temperature	T _J , T _{Stg}		-55	-	175	°C
Thermal resistance, junction to mount		R _{thJM} ⁽¹⁾		-	16	20	
Thermal resistance, junction to ambient		R _{thJA}	Device mounted on FR4 PCB, 2 oz. standard footprint	-	160	-	°C/W
VS-2EQH01HM3		Coop at de Miero CMP (DO 210AP)		2H1			
Marking device	VS-2EQH02HM3		Case style MicroSMP (DO-219AD)		2H2		

Note

⁽¹⁾ Thermal resistance junction to mount follows JEDEC® 51-14 transient dual interface test method (TDIM)

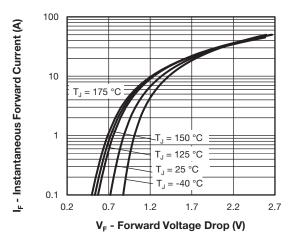


Fig. 1 - Typical Forward Voltage Drop Characteristics

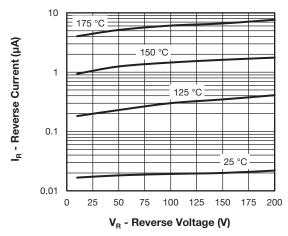


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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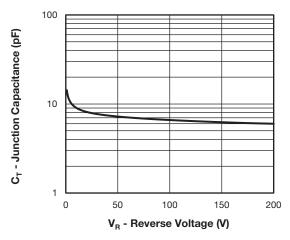


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

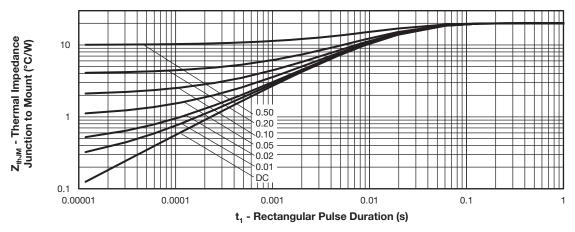


Fig. 4 - Maximum Transient Thermal Impedance, Junction to Mount

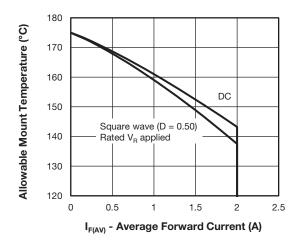


Fig. 5 - Maximum Allowable Mount Temperature vs. Average Forward Current

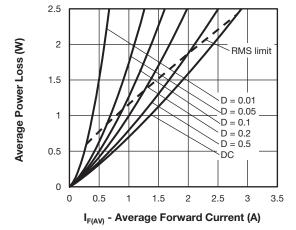
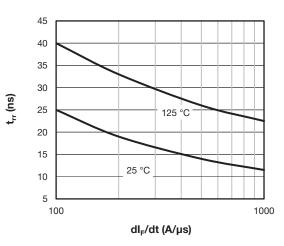


Fig. 6 - Forward Power Loss Characteristics

Note

Formula used: $T_M = T_J - (Pd + Pd_{REV}) \times R_{thJM}$; $Pd = forward power loss = I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 5); $Pd_{REV} = inverse$ power loss = $V_{R1} \times I_R$ (1 - D); I_R at $V_{R1} = rated V_R$

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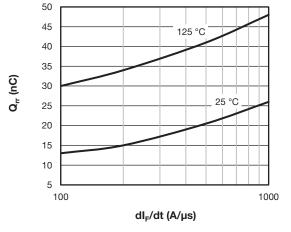
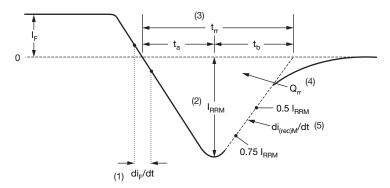


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

Fig. 8 - Typical Stored Charge vs. dl_F/dt



- (1) di_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) $\rm t_{rr}$ reverse recovery time measured from zero crossing point of negative going $\rm l_F$ to point where a line passing through 0.75 $\rm l_{RRM}$ and 0.50 $\rm l_{RRM}$ extrapolated to zero current.
- (4) \mathbf{Q}_{rr} area under curve defined by \mathbf{t}_{rr} and \mathbf{I}_{RRM}

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

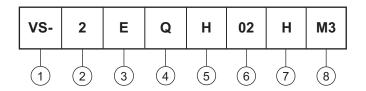
(5) di_{(rec)M}/dt - peak rate of change of current during t_b portion of t_{rr}

Fig. 9 - Reverse Recovery Waveform and Definitions

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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (2 = 2 A)

3 - Circuit configuration:

E = single diode

4 - Q = MicroSMP package

5 - Process type,

H = ultrafast recovery

6 - Voltage code (02 = 200 V)

7 - H = AEC-Q101 qualified

8 - M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N	PREFERRED PACKAGE CODE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-2EQH01HM3/H	Н	4500	7" diameter plastic tape and reel			
VS-2EQH02HM3/H	Н	4500	7" diameter plastic tape and reel			

LINKS TO RELATED DOCUMENTS					
Dimensions www.vishay.com/doc?96591					
Part marking information	www.vishay.com/doc?96590				
Packaging information	www.vishay.com/doc?88869				
SPICE model	www.vishay.com/doc?96595				



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